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May 2013

FAIRCHILD SEMICONDUCTOR®

FAN2504 200 mA CMOS LDO Regulator

Features

- Ultra-Low Power Consumption
- 200 mV Dropout Voltage at 200 mA
- Output Voltage of 3.3 V
- 75 μA Ground Current at 200 mA
- Enable / Shutdown Control
- SOT23-5 package
- Thermal Limiting
- · 300 mA Peak Current

Applications

- Mobile Phones and Accessories
- Portable Cameras and Video Recorders
- Laptop, Notebook, and Palmtop Computers

Description

The FAN2504 micropower low-dropout voltage regulator utilizes CMOS technology to offer a new level of costeffective performance in mobile handsets, laptop and notebook portable computers, and other portable devices. Features include extremely low power consumption, low shutdown current, low dropout voltage, exceptional loop stability able to accommodate a wide variety of external capacitors, and a compact SOT23-5 surfacemount package.

The FAN2504 offers significant improvements over older BiCMOS designs is are pin-compatible with many popular devices. The output is thermally protected against overload.

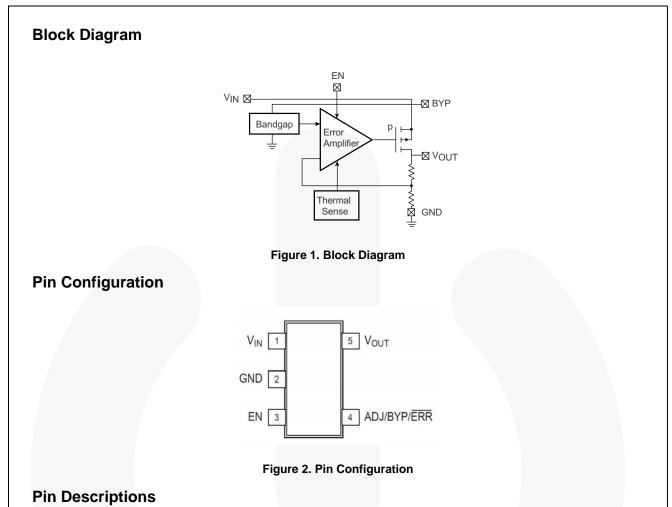
A bypass capacitor may be connected to pin 4 for optimal noise performance.

Ordering Information

Part Number	V _{OUT}	Pin 4 Function	Top Mark	Package	Packing Method
FAN2504S33X	3.3	Bypass	AG3	SOT-23 5L	Tape and Reel

Tape and Reel Information

Quantity	Reel Size	Width
3000	7 inches	8 mm



Pin Name	Pin No.	Туре	Functional Description
BYP	4	Passive	Bypass. Connect a 470 pF capacitor for noise reduction.
EN	3	. .	Enable 0: Shutdown V _{OUT} 1: Enable V _{OUT}
V _{IN}	1	Power In	Voltage Input. Supply voltage input.
V _{OUT}	5	Power Out	Voltage Output. Regulated output voltage.
GND	2	Power	Ground

Absolute Maximum Ratings⁽¹⁾

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Parameter	Min.	Max.	Unit			
Power Supply Voltages		•				
V _{IN} (Measured to GND)	0	7	V			
Enable Input (EN)		•	•			
Applied Voltage (Measured to GND) ⁽²⁾	0	7	V			
Power						
Dissipation ⁽³⁾	Inte	Internally Limited				
Temperature						
Junction	-65	150	°C			
Lead Soldering (5 s)		260	°C			
Storage	-65	150	°C			
Electrostatic Discharge ⁽⁴⁾	4		kV			

Notes:

1. Functional operation under any of these conditions is NOT implied. Performance and reliability are guaranteed only if Recommend Operating Conditions are not exceeded.

2. Applied voltage must be current limited to specified range.

3. Based upon thermally limited junction temperature:

$$P_{D} = \frac{T_{J(max)} - T_{A}}{\Theta_{JA}}$$

4. Human Body Model is 4 kV minimum using Mil Std. 883E, method 3015.7. Machine Model is 400 V minimum using JEDEC method A115-A.

Recommended Operating Conditions

The recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Nom.	Max.	Unit
V _{IN}	Input Voltage Range	2.7		6.5	V
V _{OUT}	Output Voltage Range, Adjustable	V _{REF}		$V_{IN}V_{DO}$	V
V _{EN}	Enable Input Voltage	0		V _{IN}	V
ТJ	Junction Temperature	-40		+125	°C
θ_{JA}	Thermal Resistance, Junction to Ambient		220		°C/W
θ_{JC}	Thermal Resistance, Junctions to Case	1	130		°C/W

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Electrical Characteristics^(5, 6)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
Regulator	•					I
		I _{OUT} = 100 μA		2.5	4.0	mV
		I _{OUT} = 50 mA		50	75	mV
V_{DO}	Drop-Out Voltage	I _{OUT} = 100 mA		100	140	mV
		I _{OUT} = 150 mA		150	180	mV
		I _{OUT} = 200 mA		170	200	mV
ΔV _O	Output Voltage Accuracy		-2		2	%
I _{GND}	Ground Pin Current	I _{OUT} = 200 mA			75	μA
Protection			•			•
	Current Limit		Thermally	Protecte	d	
I _{GSD}	Shutdown Current	EN = 0 V			1	μA
T _{SH}	Thermal Protection Shutdown Temperature		150			°C
Enable Inp	ut		•			
V _{IL}	Logic Low Voltage			1.2	0.4	V
V _{IH}	Logic High Voltage		2.0	1.4		V
IIH	Input Current High				1	μA
l	Input Current Low				1	μA

Switching Characteristics

	Parameter		Max.	Unit
Enable Input ⁽⁷⁾				
Response Time			500	μsec

Performance Characteristics^(5, 6)

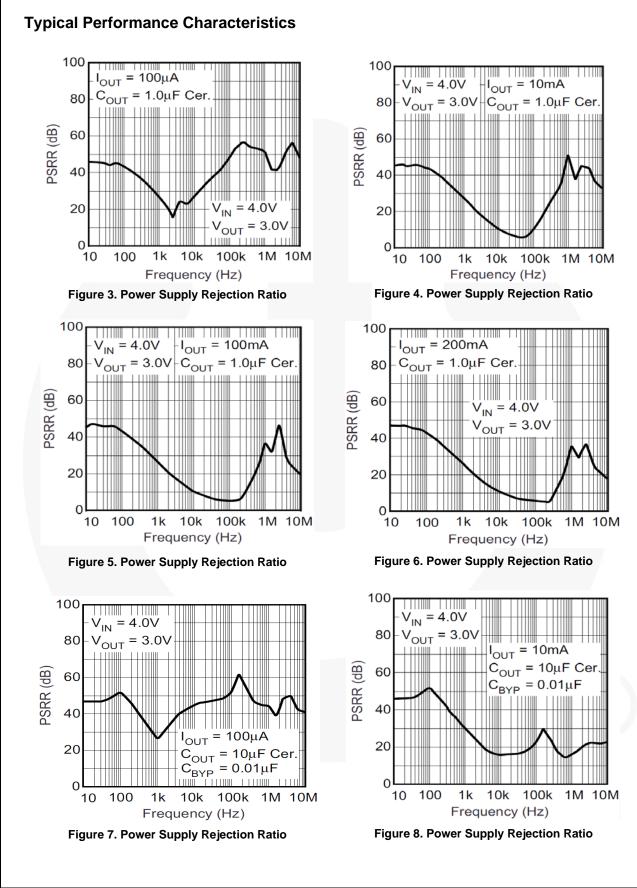
Symbol	Parameter	Conditions	Тур.	Max.	Unit
ΔV _{OUT} / ΔV _{IN}	Line Regulation	V _{IN} = (V _{OUT} + 1) to 6.5 V	0.3		% / V
ΔV _{OUT} / V _{OUT}	Load Regulation	I _{OUT} = 0.1 to 200 mA	1.0	2.0	%
	Output Noise	10 Hz - 1 kHz, C _{OUT} = 10 μF, C _{BYP} = 0.01 μF	< 7		
e _N	Output Noise	f > 10 kHz, C _{OUT} = 10 μF, C _{BYP} = 0.01 μF	< 0.01		- μV <u>/</u> /Hz
PSRR	Power Supply Rejection	f = 120 Hz at V _{IN} , C _{OUT} = 10 μF, C _{BYP} = 0.01 μF	43	(dB

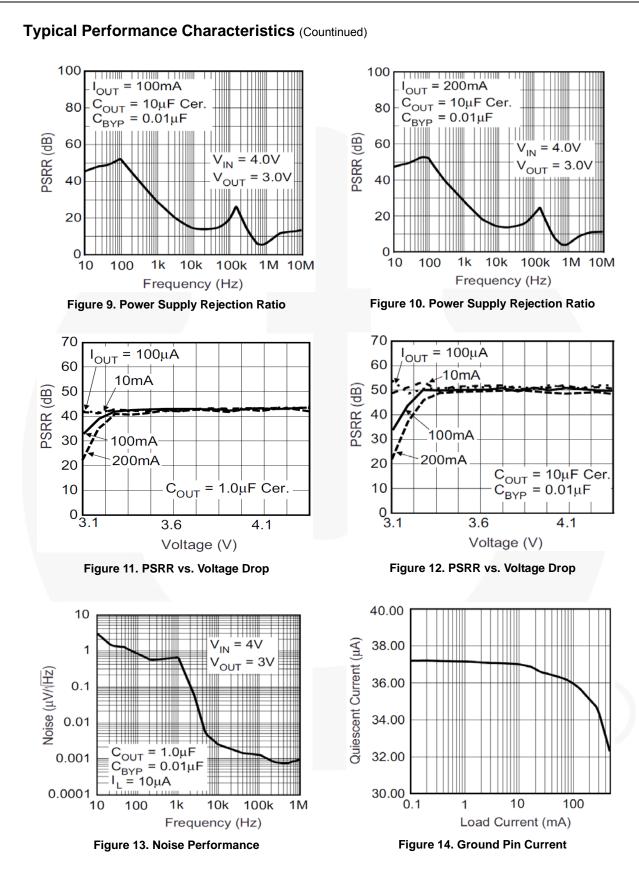
Notes:

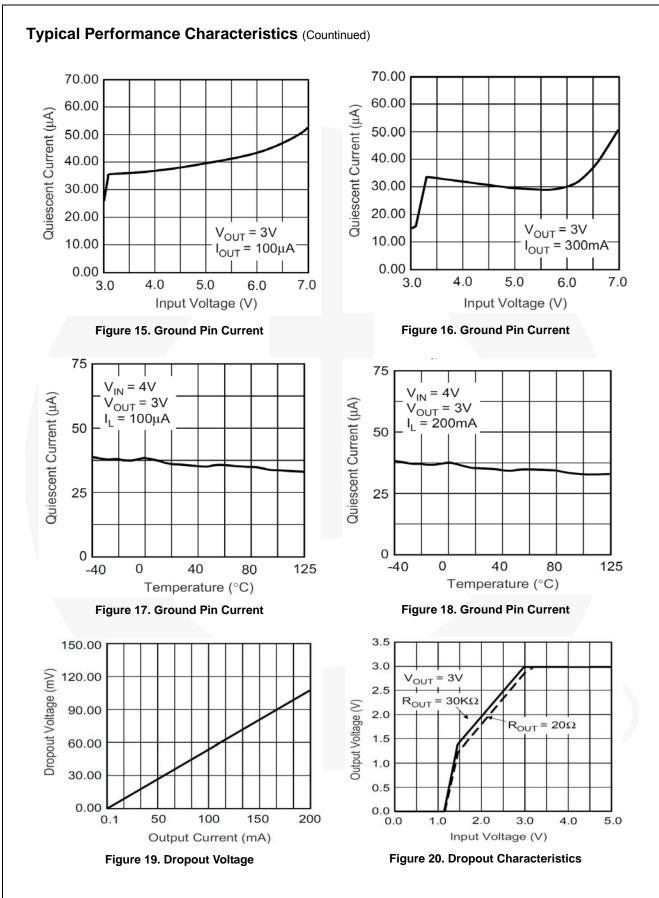
5. Unless otherwise stated; T_A = 25°C, V_{IN} = V_{OUT} + 1 V, I_{OUT} = 100 μ A, and V_{IH} > 2.0 V.

6. Bold values indicate $-40 \le T_J \le 125^{\circ}C$.

7. When using repeated cycling.







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Typical Performance Characteristics (Countinued) 8 200 Dropout Voltage (mV) Dropout Voltage (mV) 6 150 4 100 $I_{L} = 200 mA$ I_L = 100μA 2 50 0 0 0 -40 40 80 125 -40 0 40 80 125 Temperature (°C) Temperature (°C) Figure 22. Dropout Voltage Figure 21. Dropout Voltage 3.05 Enable Voltage (1V/div) Enable 3 Output Voltage (V) 2.95 Vout Output Voltage (1V/div) V_{IN} = 4V Typical 3V device 2.9 $I_{1} = 100 \mu A$ 2.85 0 40 -40 80 125 Time (20µs/div) Temperature (°C) Figure 24. Enable Pin Delay Figure 23. Out Voltage vs. Temperature Disable Voltage (1V/div) Disable Output Voltage (1V/div) VOUT Time (20µs/div) Figure 25. Shutdown Delay

Functional Description

Designed utilizing CMOS process technology, the FAN2504 is carefully optimized for use in compact battery-powered devices. It offers a unique combination of low power consumption, extremely low dropout voltages, high tolerance for a variety of output capacitors, and the ability to disable the output to less than 1 µA under user control. In the circuit, a difference amplifier controls the current through a series-pass P-channel MOSFET, comparing the load voltage at the output with an onboard low-drift bandgap reference. The series resistance of the pass P-channel MOSFET is approximately 1 Ω , resulting in an unusually low dropout voltage under load when compared to older bipolar pass-transistor designs. Protection circuitry is provided onboard for overload conditions. If the device reaches temperatures exceeding the specified maximums, an onboard circuit shuts down the output, where it remains suspended until it has cooled before re-enabling. The user can shut down the device using the enable control pin at any time.

Careful design of the output regulator amplifier assures loop stability over a wide range of ESR values in the external output capacitor. A wide range of values and types can be accomodated, allowing the user to select a capacitor meeting if space, cost, and performance requirements while enjoying reliable operation over temperature, load, and tolerance variations.

Depending on the model selected, a number of control and status functions are available to enhance the operation of the LDO regulator. An enable pin, allows the user to shut down the regulator output to conserve power, reducing supply current to less than 1 μ A. The adjustable-voltage version of the device utilize pin 4 to connect to an external voltage divider which feeds back to the regulator error amplifier, thereby setting the voltage as desired. Two other functions are available at pin 4 in the fixed-voltage version: in noise-sensitive applications, an external bypass capacitor connection is provided that allows the user to achieve optimal noise performance at the output, while the error output functions as a diagnostic flag to indicate that the output voltage has dropped more than 5% below the nominal fixed voltage.

Applications Information

External Capacitors – Selection

The FAN2504 supports a wide variety of capacitors compared to other LDO products. An innovative design approach offers significantly reduced sensitivity to ESR (Equivalent Series Resistance), which degrades regulator loop stability in older designs. While the improvements greatly simplify the design task, capacitor quality still must be considered if the designer is to achieve optimal circuit performance. In general, ceramic capacitors offer superior ESR performance, at a lower cost and a smaller case size than tantalums. Those with X7R or Y5V dielectric offer the best temperature coefficient characteristics. The combination of tolerance and variation over temperature in some capacitor types can result in significant variations, resulting in unstable performance over the rated conditions.

Input Capacitor

An input capacitor of 2.2 μ F (nominal value) or greater, connected between the input pin and ground, located in close proximity to the device, improves transient response and noise rejection. Higher values offer superior input ripple rejection and transient response. An input capacitor is recommended when the input source, either a battery or a regulated AC voltage, is located far from the device. Any good-quality ceramic, tantalum, or metal film capacitor give acceptable performance; however, tantalum capacitors with a surge current rating appropriate to the application must be selected to avoid catastrophic failure.

Output Capacitor

An output capacitor is required to maintain regulator loop stability. Unlike many other LDO regulators, the FAN2504 is nearly insensitve to output capacitor ESR. Stable operation achieved with a wide variety of capacitors with ESR values ranging from 10 m Ω to 10 Ω or more. Tantalum or aluminum electrolytic, or multilayer ceramic types can be used. A nominal value of at least 1 μ F is recommended.

Bypass Capacitor

In the fixed-voltage configuration, connecting a capacitor

between the bypass pin and ground can significantly reduce noise on the output. Values ranging from 470pF to 10 nF can be used, depending on the sensitivity to output noise in the application.

At the high-impedance Bypass pin, care must be taken in the circuit layout to minimize noise pickup. Capacitors must be selected to minimize current loading (leakage). Noise pickup from external sources can be considerable. Leakage currents into the Bypass pin directly affect regulator accuracy and should be kept as low as possible; High-quality ceramic and film types are recommended for their low leakage characteristics. Cost-sensitive applications not concerned with noise can omit this capacitor.

Control Functions

Enable Pin

Applying a voltage of 0.4 V or less at the Enable pin disables the output, reducing the quiescent output current to less than 1 μ A; while a voltage of 2.0 V or greater; enables the device. If this shutdown function is not needed, the pin can be connected to the V_{IN} pin. Allowing this pin to float causes erratic operation.

Thermal Protection

The FAN2504 can supply high peak output currents of up to 1 A for brief periods; however, this output load causes the device temperature to increase and exceed maximum ratings due to power dissipation. During output overload conditions, when the die temperature exceeds the shutdown limit temperature of 150°C, onboard thermal protection disables the output until the temperature drops below this limit; at which point, the output is then re-enabled. During a thermal shutdown situation, the user may assert the power-down function at the enable pin, reducing power consumption to the minimum level $I_{GND} \cdot V_{IN}$.

Thermal Characteristics

The FAN2504 can supply 150 mA at the specified output voltage with an operating die (junction) temperature of up to 125°C. Once the power dissipation and thermal resistance is known, the maximum junction temperature of the device can be calculated. While the power dissipation is calculated from known electrical parameters, the thermal resistance is a result of the thermal characteristics of the compact SOT23-5 surface-mount package and the surrounding PC Board copper to which it is mounted.

The power dissipation is equal to the product of the input-tooutput voltage differential and the output current plus the ground current multiplied by the input voltage, or:

$$P_{D} = (V_{IN} - V_{OUT})I_{OUT} + V_{IN}I_{GND}$$

The ground pin current, I_{GND} , can be found in the charts provided in the Electrical Characteristics section.

The relationship describing the thermal behavior of the package is:

$$\mathbf{P}_{\mathrm{D}(\mathrm{max})} = \left\{ \frac{\mathrm{T}_{\mathrm{J}(\mathrm{max})} - \mathrm{T}_{\mathrm{A}}}{\theta_{\mathrm{JA}}} \right\}$$

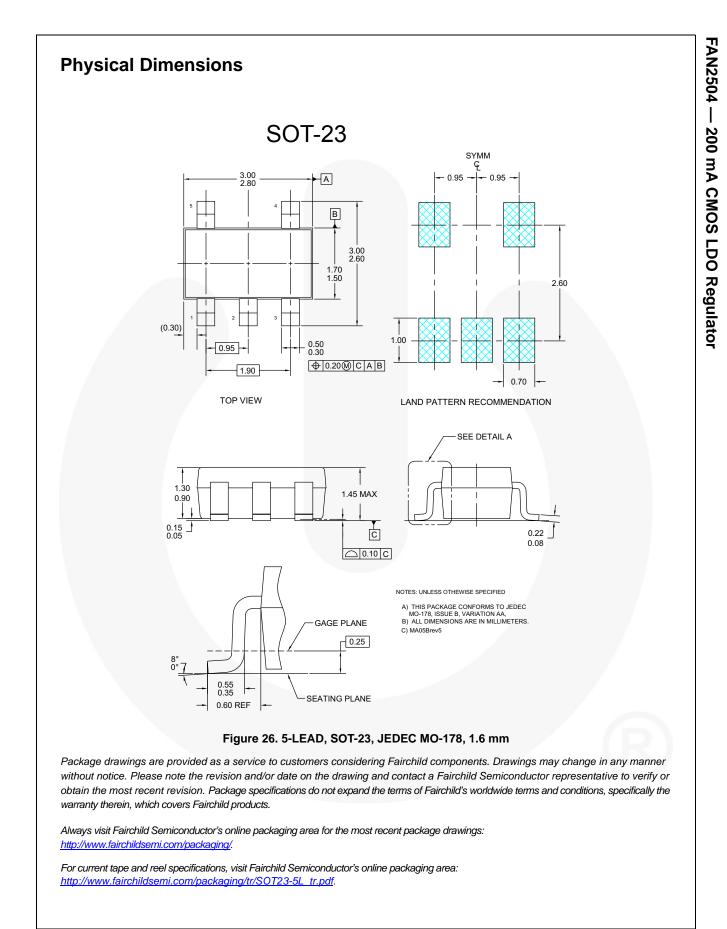
where $T_{J(max)}$ is the maximum allowable junction temperature of the die, which is 125°C, and T_A is the ambient operating temperature. θ_{JA} is dependent on the surrounding PC board layout and can be empirically obtained. While the θ_{JC} (junction-to-case) of the SOT23-5 package is specified at 130°C/W, the θ_{JA} of the minimum PWB footprint will be at least 235°C/W. This can be improved upon by providing a heat sink of surrounding copper ground on the PCB. Depending on the size of the copper area, the resulting θ_{JA} can range from approximately 180°C/W for one square inch to nearly 130°C/W for four square inches. The addition of backside copper with through-holes, stiffeners, and other enhancements can reduce this value. The heat contributed by the dissipation of other devices located nearby must be included

in design considerations.

Once the limiting parameters in these two relationships have been determined, the design can be modified to ensure that the device remains within specified operating conditions. If overload conditions are not considered, it is possible for the device to enter a thermal cycling loop, in which the circuit enters a shutdown condition, cools, reenables, and then again overheats and shuts down repeatedly due to an unmanaged fault condition.

General PCB Layout Considerations

To achieve the full performance of the device, careful circuit layout and grounding technique must be observed. Establishing a small local ground, to which the GND pin and the output and bypass capacitors are connected, is recommended. The input capacitor should be grounded to the main ground plane. The quiet local ground is routed back to the main ground plane using feed-through vias. In general, the high-frequency compensation components (input, bypass, and output capacitors) should be located as close to the device as possible. The proximity of the output capacitor is especially important to achieve optimal noise compensation from the onboard error amplifier, especially during high load conditions. A large copper area in the local ground provides the heat sinking discussed above when high power dissipation significantly increases the temperature of the device. Component-side copper provides significantly better thermal performance for this surface-mount device, compared to that obtained when using only copper planes on the underside.



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